

AMSE205 Thermodynamics I

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Problem Set #3

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1. Calculate ΔH_{1600} and ΔS_{1600} for the reaction $\text{Zr}(\beta) + \text{O}_2 = \text{ZrO}_2(\beta)$.
(Utilize the Tables in the APPENDIX of the textbook.)

2. Calculate the value of ΔG for the reaction



at 800 K. What percentage error occurs if it is assumed that ΔC_p for the reaction is zero?

3. 모든 결정은 원자가 일정한 격자 자리에 위치하고 있다. 원자가 있어야 할 격자 자리가 비어 있는 경우 원자공공 (vacancy)이 발생했다고 한다. Vacancy formation energy 는 vacancy 가 하나 생겼을 때 증가하는 system 의 에너지를 말하며 ΔH_v 로 표시한다. N 개의 격자 자리로 이루어진 순수 결정에서 평형 vacancy 수 (n) 또는 vacancy 와 총 격자 자리 개수 비율 (n/N)의 표현 식을, 통계열역학적 접근 방식과 고전열역학적 접근 방식을 사용하여 각각 유도하시오.

Problem Set #3.

20200865 정세희

책에는 298K 기준 나옴. 298K 기준으로
찾자.

1. Calculate ΔH_{1600} and ΔS_{1600} for the reaction $\text{Zr}(\beta) + \text{O}_2 = \text{ZrO}_2(\beta)$.
(Utilize the Tables in the APPENDIX of the textbook.)

→ 1136K에서 transition

a) ΔH_{1600} : $\text{Zr}(\beta) + \text{O}_2 = \text{ZrO}_2(\beta)$

1478 K에서 transition 발생 ($\alpha \rightarrow \beta$)

$$\Delta H_{1600} = \Delta H_{\text{ZrO}_2(\beta)} - (\Delta H_{\text{Zr}(\beta), 1600} + \Delta H_{\text{O}_2, 1600})$$

$$\begin{aligned} \Delta H_{\text{ZrO}_2(\beta)} &= \Delta H_{\text{ZrO}_2(\alpha)} + \Delta H_{\alpha \rightarrow \beta} + \int_{298}^{1478} \Delta C_{p,\alpha} dT + \int_{1478}^{1600} \Delta C_{p,\beta} dT \\ &= -1100800 + 5900 + \int_{298}^{1478} (69.62 + 7.53 \times 10^{-3} T - \frac{14.06 \times 10^5}{T^2}) dT \\ &\quad + \int_{1478}^{1600} 74.48 dT \end{aligned}$$

$$\begin{aligned} &= -1100800 + 5900 + \left[69.62T + 3.765 \times 10^{-3} T^2 + 14.06 \times 10^5 \cdot \frac{1}{T} \right]_{298}^{1478} \\ &\quad + 74.48(1600 - 1478) \end{aligned}$$

$$= -1094900 + (112517.63 - 25888.63) + 9086.56 = -999538 \text{ (J)}$$

$$\begin{aligned} \Delta H_{\text{Zr}(\beta), 1600} &= \Delta H_{\text{Zr}(\alpha)} + \Delta H_{\alpha \rightarrow \beta} + \int_{298}^{1136} \Delta C_{p,\alpha} dT + \int_{1136}^{1600} \Delta C_{p,\beta} dT \\ &= 3900 + \int_{298}^{1136} (21.97 + 11.63 \times 10^{-3} T) dT \\ &\quad + \int_{1136}^{1600} (23.22 + 4.64 \times 10^{-3} T) dT \end{aligned}$$

$$\begin{aligned} &= 3900 + \left[21.97T + 5.815 \times 10^{-3} T^2 \right]_{298}^{1136} \\ &\quad + \left[23.22T + 2.32 \times 10^{-3} T^2 \right]_{1136}^{1600} \end{aligned}$$

$$= 43018 \text{ (J)}$$

$$\begin{aligned} \Delta H_{\text{O}_2, 1600} &= \int_{298}^{1600} C_p dT \\ &= \int_{298}^{1600} (29.96 + 4.18 \times 10^{-3} T - 1.67 \times 10^5 \cdot \frac{1}{T^2}) dT \end{aligned}$$

$$= \left[29.96T + 2.09 \times 10^{-3} T^2 + 1.67 \times 10^5 \times \frac{1}{T} \right]_{298}^{1600}$$

$$= 53390.78 - 9674.08 = 43716.7 \text{ (J)}$$

$$\therefore \Delta H_{1600} = -999536 - (43018 + 43717) = -1,086 \times 10^6 \text{ (J)}$$

$$b) \Delta S_{1600}$$

$$\Delta S_{1600} = S_{ZrO_2(p), 1600} - (S_{Zr(p), 1600} + S_{O_2(p), 1600})$$

$$\begin{aligned} S_{ZrO_2(p), 1600} &= S_{ZrO_2(p), 298} + \int_{298}^{1498} \frac{C_{p,ZrO_2(p)}}{T} dT + \int_{1498}^{1600} \frac{C_{p,ZrO_2(p)}}{T} dT + \Delta S_{\alpha \rightarrow \beta} \\ &= 50.4 + \int_{298}^{1498} \frac{69.62}{T} + 7.53 \times 10^{-3} - \frac{14.06 \times 10^5}{T^3} dT + \Delta S_{\alpha \rightarrow \beta} \\ &\quad + \int_{1498}^{1600} \frac{74.48}{T} dT \\ &= 50.4 + \left[69.62 \ln T + 7.53 \times 10^{-3} T + \frac{1}{2} \frac{14.06 \times 10^5}{T^2} \right]_{298}^{1498} + 74.48 \ln \frac{1600}{1498} + \frac{5900}{1498} \\ &= 173.08 \text{ (J/K)} \end{aligned}$$

$$\begin{aligned} S_{Zr(p), 1600} &= S_{Zr(p), 298} + \int_{298}^{1136} \frac{C_{p,Zr(p)}}{T} dT + \int_{1136}^{1600} \frac{C_{p,Zr(p)}}{T} dT + \Delta S_{\alpha \rightarrow \beta} \\ &= 39 + \int_{298}^{1136} \frac{21.97}{T} + 11.63 \times 10^{-3} dT \\ &\quad + \int_{1136}^{1600} \frac{23.22}{T} + 4.64 \times 10^{-3} dT + \frac{3900}{1136} \\ &= 39 + \left[21.97 \ln T + 11.63 \times 10^{-3} T \right]_{298}^{1136} \\ &\quad + \left[23.22 \ln T + 4.64 \times 10^{-3} T \right]_{1136}^{1600} + \frac{3900}{1136} \\ &= 91.684 \end{aligned}$$

$$\begin{aligned} S_{O_2(p), 1600} &= S_{O_2(p), 298} + \int_{298}^{1600} \frac{29.96}{T} + 4.18 \times 10^{-3} - \frac{1.67 \times 10^5}{T^3} dT \\ &= 205.1 + \left[29.96 \ln T + 4.18 \times 10^{-3} T + 0.835 \times 10^5 \frac{1}{T^2} \right]_{298}^{1600} \\ &= 259.99 \end{aligned}$$

$$\Rightarrow \Delta S_{1600} = -178.6 \text{ J/K}$$

2. Calculate the value of ΔG for the reaction



at 800 K. What percentage error occurs if it is assumed that ΔC_p for the reaction is zero?

① 800 K में ΔG

$$\Delta G_{800} = \Delta H_{800} - T \Delta S_{800} = \Delta H_{800} - 800 \Delta S_{800}$$

$$\therefore \Delta H_{800} = 3 \Delta H_{\text{SiO}_2 (\alpha\text{-quartz})} + 2 \Delta H_{\text{N}_2} - \Delta H_{\text{Si}_3\text{N}_4} - 3 \Delta H_{\text{O}_2}$$

$$\Delta H_{\text{SiO}_2 (\alpha\text{-quartz}), 800} = \Delta H_{\text{SiO}_2, 298} + \int_{298}^{800} \Delta C_p dT$$

$$= -910900 + \int_{298}^{800} 43.89 + 10^{-3} T - \frac{6.02 \times 10^5}{T^2} dT$$

$$= -910900 + \left[43.89 T + \frac{1}{2} \times 10^{-3} T^2 + 6.02 \times 10^5 \times \frac{1}{T} \right]_{298}^{800}$$

$$= -889859.26$$

$$\Delta H_{\text{N}_2} = \Delta H_{\text{N}_2, 298} + \int_{298}^{800} \Delta C_p dT$$

$$= \int_{298}^{800} 27.87 + 4.27 \times 10^{-3} T dT$$

$$= \left[27.87 T + 2.135 \times 10^{-3} T^2 \right]_{298}^{800} = 15167.5$$

$$\Delta H_{\text{Si}_3\text{N}_4} = \Delta H_{\text{Si}_3\text{N}_4, 298} + \int_{298}^{800} \Delta C_p dT$$

$$= -744800 + \int_{298}^{800} 10.54 + 98.74 \times 10^{-3} \times T dT$$

$$= -744800 + \left[10.54 T + 49.37 \times 10^{-3} \times T^2 \right]_{298}^{800}$$

$$= -682176.4$$

$$\Delta H_{\text{O}_2, 800} = \Delta H_{\text{O}_2, 298} + \int_{298}^{800} \Delta C_p dT$$

$$= \int_{298}^{800} 29.96 + 4.18 \times 10^{-3} T - 1.67 \times 10^5 \times \frac{1}{T^2} dT$$

$$= \left[29.96 T + 2.09 \times 10^{-3} T^2 + 1.67 \times 10^5 \times \frac{1}{T} \right]_{298}^{800}$$

$$= 15840.27$$

$$\therefore \Delta H_{800} = -2004587.2 (\text{J})$$

$$(i) \Delta S_{800} = 3 S_{SiO_2, 800} + 2 S_{N_2, 800} - S_{Si_3N_4, 800} - 3 S_{O_2, 800}$$

$$\begin{aligned} S_{SiO_2, 800} &= S_{SiO_2, 298} + \int_{298}^{800} \Delta C_p dT \\ &= 41.5 + \int_{298}^{800} \frac{43.89}{T} + 10^{-3} - 6.02 \times 10^{-5} \times \frac{1}{T^2} dT \\ &= 41.5 + \left[43.89 \ln T + T + 3.01 \times 10^{-3} \times \frac{1}{T} \right]_{298}^{800} \\ &= 82.425 \end{aligned}$$

$$\begin{aligned} S_{N_2, 800} &= S_{N_2, 298} + \int_{298}^{800} \Delta C_p dT \\ &= 191.5 + \int_{298}^{800} \frac{27.87}{T} + 4.27 \times 10^{-3} dT \\ &= 191.5 + \left[27.87 \ln T + 4.27 \times 10^{-3} T \right]_{298}^{800} = 221.17 \end{aligned}$$

$$\begin{aligned} S_{Si_3N_4, 800} &= S_{Si_3N_4, 298} + \int_{298}^{800} \Delta C_p dT \\ &= 113 + \int_{298}^{800} \frac{70.54}{T} + 98.74 \times 10^{-3} dT \\ &= 113 + \left[70.54 \ln T + 98.74 \times 10^{-3} T \right]_{298}^{800} \\ &= 232.23 (J/K) \end{aligned}$$

$$\begin{aligned} S_{O_2, 800} &= S_{O_2, 298} + \int_{298}^{800} \Delta C_p dT \\ &= 205.1 + \int_{298}^{800} 29.96 \times \frac{1}{T} + 4.18 \times 10^{-3} - 1.67 \times 10^{-5} \times \frac{1}{T^2} dT \\ &= 205.1 + \left[29.96 \ln T + 4.18 \times 10^{-3} T + 0.835 \times 10^{-5} \times \frac{1}{T} \right]_{298}^{800} \\ &= 235.9746 \end{aligned}$$

$$\begin{aligned} \therefore \Delta S_{800} &= 3 \times 82.425 + 2 \times 221.17 - 232.23 - 3 \times 235.9746 \\ &= -250.5388 \end{aligned}$$

$$\begin{aligned} \therefore \Delta G_{800} &= \Delta H_{800} - 800 \Delta S_{800} = -200457.1 - 2 \times 800 \times 250.5388 \\ &= \boxed{-180415.6 (J)} \end{aligned}$$

$\Delta C_p = 0$ 이라 가정하면,

$$\Delta G = \Delta H - T\Delta S$$

$$\Delta H = -910900 \times 3 + 744800 = -1987900$$

$$\Delta S = 3 \times 41.5 + 2 \times 191.5 - 113 - 3 \times 205.1 = -220.8$$

$$\Delta G = -1987900 + 800 \times 220.8 = -1811260$$

$$\therefore \text{error} = \frac{1811260 - 1804156}{1804156} \times 100(\%) \approx 0.394(\%)$$

$$\Delta G = -1804156 \text{ J}, \text{ error} = 0.394\%$$

3. 모든 결정은 원자가 일정한 격자 자리에 위치하고 있다. 원자가 있어야 할 격자 자리가 비어 있는 경우 원자공공 (vacancy)이 발생했다고 한다. Vacancy formation energy 는 vacancy 가 하나 생겼을 때 증가하는 system 의 에너지를 말하며 ΔH_v 로 표시한다. N 개의 격자 자리로 이루어진 순수 결정에서 평형 vacancy 수 (n) 또는 vacancy 와 총 격자 자리 개수 비율 (n/N)의 표현 식을, 통계열역학적 접근 방식과 고전열역학적 접근 방식을 사용하여 각각 유도하시오.

vacancy formation energy : vacancy 하나 생길 때 증가하는 System의 E. ΔH_v

① 통계열역학적 접근 방식

N개의 격자자리

vacancy

$$Z = \sum_i \exp\left(-\frac{E_i}{kT}\right) = 1 + e^{-\frac{\Delta H}{kT}}$$

atom의 경우! $e^0 = 1$

$$\therefore p = \frac{e^{-\frac{\Delta H}{kT}}}{1 + e^{-\frac{\Delta H}{kT}}} = \frac{1}{e^{\frac{\Delta H}{kT}} + 1}$$

②

② 고전열역학적 방식

$$\Delta S = k \ln \frac{N!}{(N-n)!} = k (\ln N! - \ln(N-n)!))$$

$$= k (N \ln N - n \ln n - (N-n) \ln(N-n))$$

$$= k ((N-n) \ln N - (N-n) \ln(N-n) + n \ln N - n \ln n)$$

$$= k (N-n) \ln \frac{N}{N-n} + k n \ln \frac{N}{n}$$

$$F = U - ST \Rightarrow \Delta F = \Delta U - T \Delta S$$

$$= n_v \Delta H_v - T k (N-n) \ln \frac{N}{N-n} - T k n \ln \frac{N}{n}$$

$$\frac{dF}{dn} = \Delta H_v - T k \left(-\cancel{\ln N} + \ln(N-n) \right) + \ln \frac{N}{n} \quad \left(\frac{\ln N - \ln n}{\ln N - \ln n} \right)$$

$$= \Delta H_v - T k \ln \frac{N-n}{n} = 0$$

$$T k \ln \frac{N-n}{n} = \Delta H_v \quad \ln \frac{N-n}{n} = \frac{\Delta H_v}{T k}$$

$$\frac{N-n}{n} = e^{\frac{\Delta H_v}{T k}} \rightarrow \frac{N}{n} = e^{\frac{\Delta H_v}{T k}} + 1$$

$$\therefore \frac{n}{N} = \frac{1}{1 + e^{\frac{\Delta H_v}{T k}}}$$